

MicroSIZE, Single-Supply CMOS OPERATIONAL AMPLIFIERS MicroAmplifier™ Series

FEATURES

- **MicroSIZE PACKAGES:**
SOT23-5, SOT23-8
- **SINGLE-SUPPLY OPERATION**
- **RAIL-TO-RAIL OUTPUT SWING**
- **FET-INPUT:** $I_B = 10\text{pA max}$
- **HIGH SPEED:**
OPA337: 3MHz, $1.2\text{V}/\mu\text{s}$ ($G = 1$)
OPA338: 12.5MHz, $4.6\text{V}/\mu\text{s}$ ($G = 5$)
- **OPERATION FROM 2.5V to 5.5V**
- **HIGH OPEN-LOOP GAIN:** 120dB
- **LOW QUIESCENT CURRENT:** $525\mu\text{A/amp}$
- **SINGLE AND DUAL VERSIONS**

APPLICATIONS

- BATTERY-POWERED INSTRUMENTS
- PHOTODIODE PRE-AMPS
- MEDICAL INSTRUMENTS
- TEST EQUIPMENT
- AUDIO SYSTEMS
- DRIVING ADCs
- CONSUMER PRODUCTS

SPICE model available at www.ti.com.

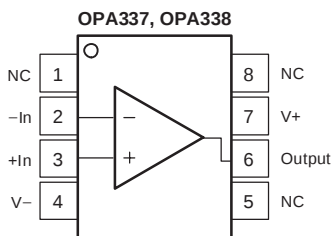
DESCRIPTION

The OPA337 and OPA338 series rail-to-rail output CMOS operational amplifiers are designed for low cost and miniature applications. Packaged in the SOT23-8, the OPA2337EA and OPA2338EA are Texas Instruments' smallest dual op amps. At 1/4 the size of a conventional SO-8 surface-mount, they are ideal for space-sensitive applications.

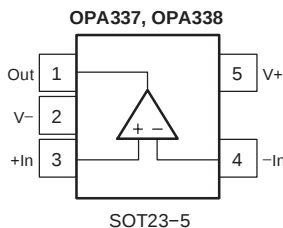
Utilizing advanced CMOS technology, the OPA337 and OPA338 op amps provide low bias current, high-speed operation, high open-loop gain, and rail-to-rail output swing. They operate on a single supply with operation as low as 2.5V while drawing only $525\mu\text{A}$ quiescent current. In addition, the input common-mode voltage range includes ground—ideal for single-supply operation.

The OPA337 series is unity-gain stable. The OPA338 series is optimized for gains greater than or equal to 5. They are easy-to-use and free from phase inversion and overload problems found in some other op amps. Excellent performance is maintained as the amplifiers swing to their specified limits. The dual versions feature completely independent circuitry for lowest crosstalk and freedom from interaction, even when overdriven or overloaded.

PACKAGE	G = 1 STABLE		G ≥ 5 STABLE	
	SINGLE OPA337	DUAL OPA2337	SINGLE OPA338	DUAL OPA2338
SOT23-5	✓		✓	
SOT23-8		✓		✓
MSOP-8	✓			
SO-8	✓	✓	✓	✓
DIP-8	✓	✓		

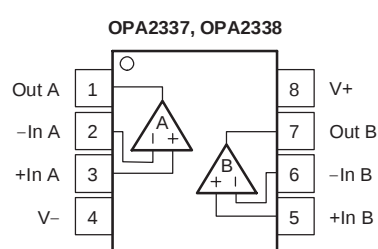


DIP-8⁽¹⁾, SO-8, MSOP-8⁽¹⁾
NC = No Connection



SOT23-5

NOTE: (1) DIP AND MSOP-8 versions for OPA337, OPA2337 only.



DIP-8⁽¹⁾, SO-8, SOT23-8



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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ABSOLUTE MAXIMUM RATINGS(1)

Supply Voltage	7.5V
Input Voltage(2)	(V–) – 0.5V to (V+) + 0.5V
Input Current(2)	10mA
Output Short Circuit(3)	Continuous
Operating Temperature	–55°C to +125°C
Storage Temperature	–55°C to +125°C
Junction Temperature	150°C
Lead Temperature (soldering, 10s)	300°C

(1) Stresses above these ratings may cause permanent damage.

Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not supported.

(2) Input signal voltage is limited by internal diodes connected to power supplies. See text.

(3) Short-circuit to ground, one amplifier per package.



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

ORDERING INFORMATION(1)

PRODUCT	DESCRIPTION	PACKAGE-LEAD	PACKAGE DESIGNATOR	SPECIFIED TEMPERATURE RANGE	PACKAGE MARKING	ORDERING NUMBER	TRANSPORT MEDIA, QUANTITY
OPA337 Series	Single, G = 1 Stable	SOT23-5	DBV	–40°C to +85°C	C37	OPA337NA/250	Tape and Reel, 250
		MSOP-8	DGK		G37	OPA337NA/3K	Tape and Reel, 3000
		DIP-8	P		OPA337PA	OPA337EA/250	Tape and Reel, 250
		SO-8	D		OPA337UA	OPA337EA/2K5	Tape and Reel, 2500
		Surface-Mount			OPA337UA	OPA337PA	Rails
OPA2337	Dual, G = 1 Stable	SOT23-8	DCN	–40°C to +85°C	A7	OPA337UA	Rails
		DIP-8	P		OPA2337PA	OPA337UA/2K5	Tape and Reel, 2500
		SO-8	D		OPA2337UA		
		Surface-Mount					
OPA338 Series	Single, G ≥ 5 Stable	SOT23-5	DBV	–40°C to +85°C	A38	OPA2337EA/250	Tape and Reel, 250
		SO-8	D		OPA338UA	OPA2337EA/3K	Tape and Reel, 3000
		Surface-Mount			OPA338UA	OPA2337PA	Rails
						OPA2337UA	Rails
						OPA2337UA/2K5	Tape and Reel, 2500
OPA2338	Dual, G ≥ 5 Stable	SOT23-8	DCN	–40°C to +85°C	A8	OPA2338EA/250	Tape and Reel, 250
		SO-8	D		OPA2338UA	OPA2338EA/3K	Tape and Reel, 3000
		Surface-Mount			OPA2338UA	OPA2338UA	Rails
						OPA2338UA/2K5	Tape and Reel, 2500

(1) For the most current package and ordering information, see the Package Option Addendum located at the end of this data sheet.

ELECTRICAL CHARACTERISTICS: $V_S = 2.7V$ to $5.5V$
Boldface limits apply over the specified temperature range, $-40^{\circ}C$ to $+85^{\circ}C$, $V_S = 5V$.

At $T_A = +25^{\circ}C$ and $R_L = 25k\Omega$ connected to $V_S/2$, unless otherwise noted.

PARAMETER	CONDITION	OPA337, OPA2337, OPA338, OPA2338			UNIT
		MIN	TYP(1)	MAX	
OFFSET VOLTAGE					
Input Offset Voltage V_{OS}			± 0.5	± 3	mV
$T_A = -40^{\circ}C$ to $+85^{\circ}C$				± 3.5	mV
vs Temperature dV_{OS}/dT			± 2		$\mu V/^{\circ}C$
vs Power-Supply Rejection Ratio PSRR			25	125	$\mu V/V$
$T_A = -40^{\circ}C$ to $+85^{\circ}C$				125	$\mu V/V$
Channel Separation (dual versions)	$V_S = 2.7V$ to $5.5V$ dc		0.3		$\mu V/V$
INPUT BIAS CURRENT					
Input Bias Current I_B			± 0.2	± 10	pA
$T_A = -40^{\circ}C$ to $+85^{\circ}C$			See Typical Curve		
Input Offset Current I_{OS}			± 0.2	± 10	pA
NOISE					
Input Voltage Noise, $f = 0.1Hz$ to $10Hz$			6		μV_{PP}
Input Voltage Noise Density, $f = 1kHz$ e_n			26		$nV/\sqrt{Hz}$
Current Noise Density, $f = 1kHz$ i_n			0.6		$fA/\sqrt{Hz}$
INPUT VOLTAGE RANGE					
Common-Mode Voltage Range V_{CM}	$T_A = -40^{\circ}C$ to $+85^{\circ}C$	-0.2		$(V+) - 1.2$	V
Common-Mode Rejection Ratio CMRR	$-0.2V < V_{CM} < (V+) - 1.2V$	74	90		dB
$T_A = -40^{\circ}C$ to $+85^{\circ}C$	$-0.2V < V_{CM} < (V+) - 1.2V$	74			dB
INPUT IMPEDANCE					
Differential			$10^{13} 2$		ΩpF
Common-Mode			$10^{13} 4$		ΩpF
OPEN-LOOP GAIN					
Open-Loop Voltage Gain A_{OL}	$R_L = 25k\Omega$, $125mV < V_O < (V+) - 125mV$	100	120		dB
$T_A = -40^{\circ}C$ to $+85^{\circ}C$	$R_L = 25k\Omega$, $125mV < V_O < (V+) - 125mV$	100			dB
	$R_L = 5k\Omega$, $500mV < V_O < (V+) - 500mV$	100	114		dB
$T_A = -40^{\circ}C$ to $+85^{\circ}C$	$R_L = 5k\Omega$, $500mV < V_O < (V+) - 500mV$	100			dB
OPA337 FREQUENCY RESPONSE					
Gain-Bandwidth Product GBW	$V_S = 5V$, $G = 1$		3		MHz
Slew Rate SR	$V_S = 5V$, $G = 1$		1.2		$V/\mu s$
Settling Time: 0.1%	$V_S = 5V$, 2V Step, $C_L = 100pF$, $G = 1$		2		μs
0.01%	$V_S = 5V$, 2V Step, $C_L = 100pF$, $G = 1$		2.5		μs
Overload Recovery Time	$V_{IN} \times G = V_S$		2		μs
Total Harmonic Distortion + Noise THD+N	$V_S = 5V$, $V_O = 3V_{PP}$, $G = 1$, $f = 1kHz$		0.001		%
OPA338 FREQUENCY RESPONSE					
Gain-Bandwidth Product GBW	$V_S = 5V$, $G = 5$		12.5		MHz
Slew Rate SR	$V_S = 5V$, $G = 5$		4.6		$V/\mu s$
Settling Time: 0.1%	$V_S = 5V$, 2V Step, $C_L = 100pF$, $G = 5$		1.4		μs
0.01%	$V_S = 5V$, 2V Step, $C_L = 100pF$, $G = 5$		1.9		μs
Overload Recovery Time	$V_{IN} \times G = V_S$		0.5		μs
Total Harmonic Distortion + Noise THD+N	$V_S = 5V$, $V_O = 3V_{PP}$, $G = 5$, $f = 1kHz$		0.0035		%

(1) $V_S = 5V$.

(2) Output voltage swings are measured between the output and negative and positive power-supply rails.

ELECTRICAL CHARACTERISTICS: $V_S = 2.7V$ to $5.5V$ (continued)

Boldface limits apply over the specified temperature range, $-40^{\circ}C$ to $+85^{\circ}C$, $V_S = 5V$.

At $T_A = +25^{\circ}C$ and $R_L = 25k\Omega$ connected to $V_S/2$, unless otherwise noted.

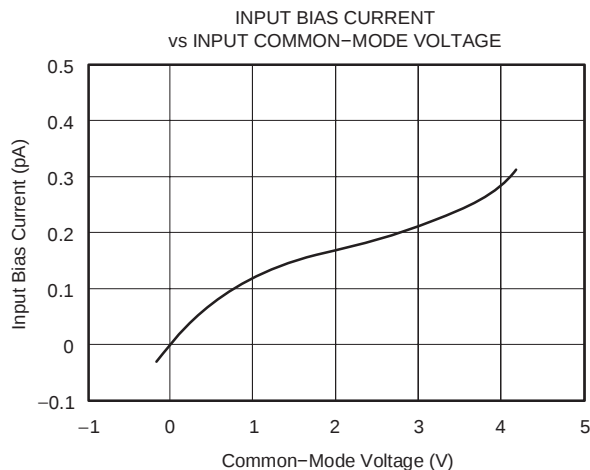
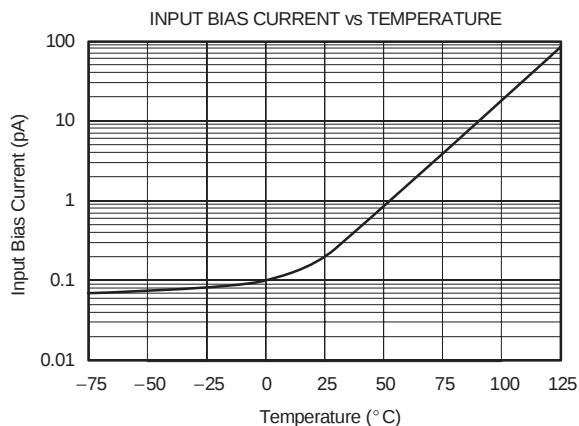
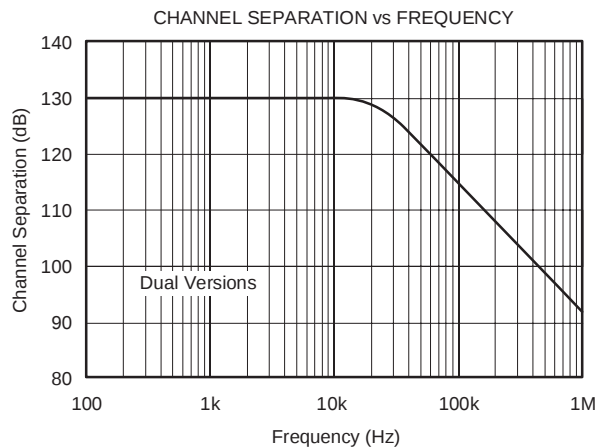
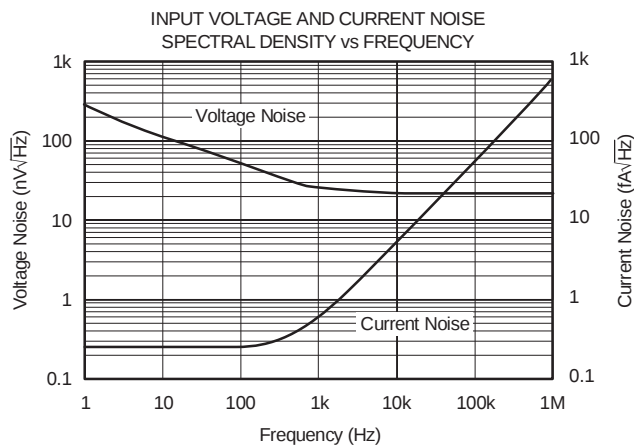
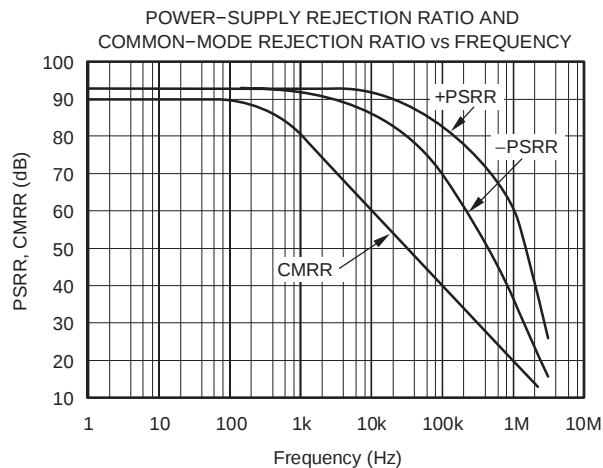
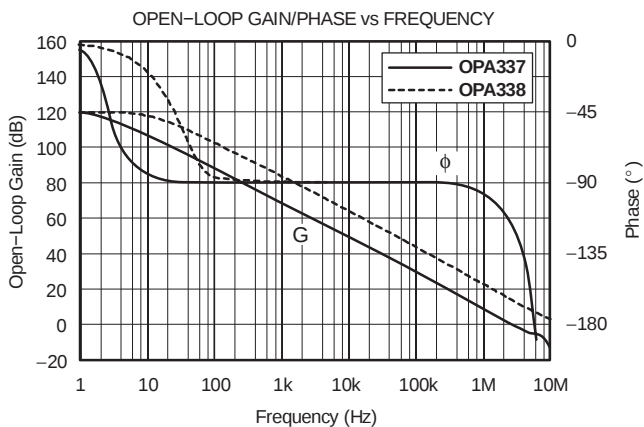
PARAMETER	CONDITION	OPA337, OPA2337, OPA338, OPA2338			UNIT
		MIN	TYP(1)	MAX	
OUTPUT					
Voltage Output Swing from Rail(2)	$R_L = 25k\Omega$, $A_{OL} \geq 100dB$		40	125	mV
$T_A = -40^{\circ}C$ to $+85^{\circ}C$	$R_L = 25k\Omega$, $A_{OL} \geq 100dB$			125	mV
	$R_L = 5k\Omega$, $A_{OL} \geq 100dB$		150	500	mV
$T_A = -40^{\circ}C$ to $+85^{\circ}C$	$R_L = 5k\Omega$, $A_{OL} \geq 100dB$			500	mV
Short-Circuit Current			± 9		mA
Capacitive Load Drive		See Typical Curve			
POWER SUPPLY					
Specified Voltage Range	V_S	2.7		5.5	V
Minimum Operating Voltage			2.5		V
Quiescent Current (per amplifier)	I_Q		0.525	1	mA
$T_A = -40^{\circ}C$ to $+85^{\circ}C$	$I_O = 0$ $I_O = 0$			1.2	mA
TEMPERATURE RANGE					
Specified Range		-40		+85	$^{\circ}C$
Operating Range		-55		+125	$^{\circ}C$
Storage Range		-55		+125	$^{\circ}C$
Thermal Resistance	θ_{JA}				
SOT23-5 Surface-Mount			200		$^{\circ}C/W$
SOT23-8 Surface-Mount			200		$^{\circ}C/W$
MSOP-8			150		$^{\circ}C/W$
SO-8 Surface-Mount			150		$^{\circ}C/W$
DIP-8			100		$^{\circ}C/W$

(1) $V_S = 5V$.

(2) Output voltage swings are measured between the output and negative and positive power-supply rails.

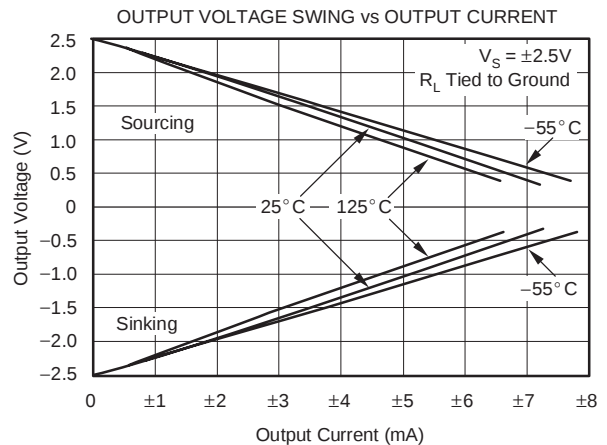
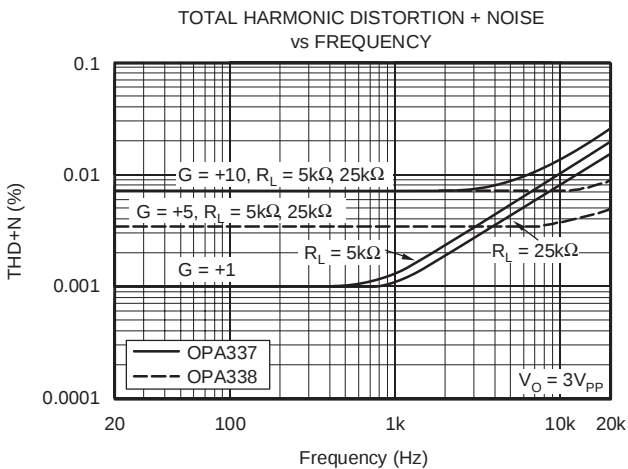
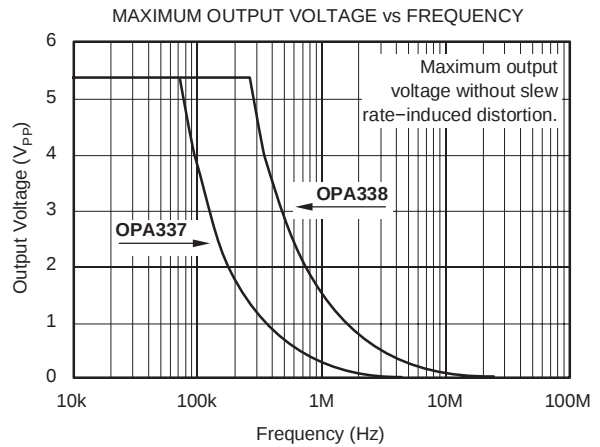
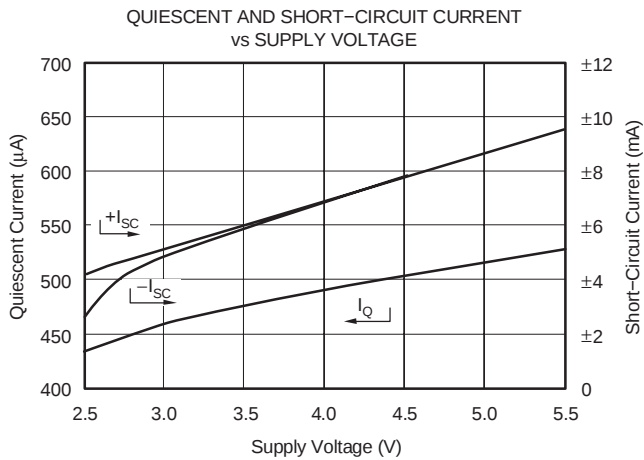
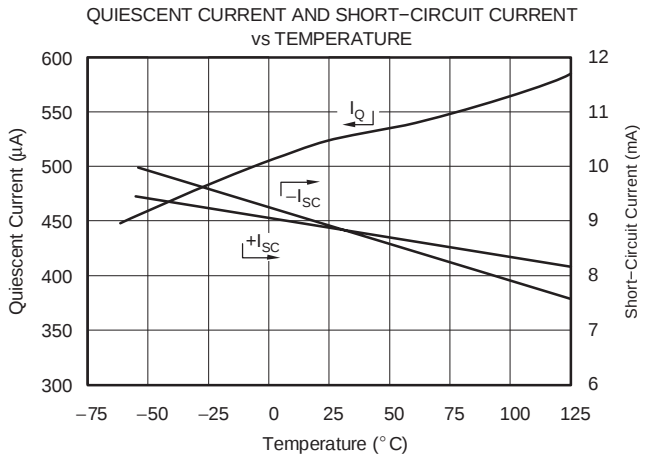
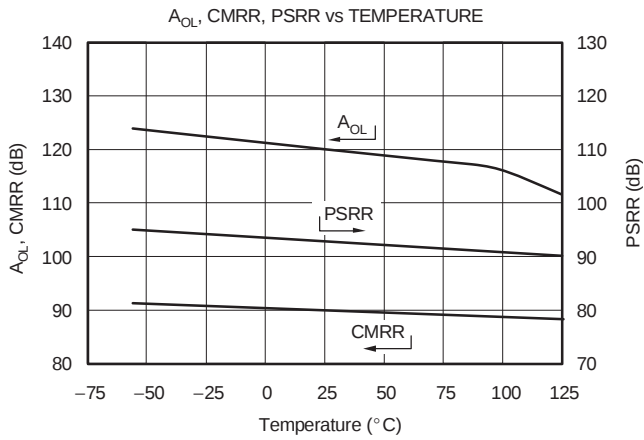
TYPICAL CHARACTERISTICS

At $T_A = +25^\circ\text{C}$, $V_S = +5\text{V}$, and $R_L = 25\text{k}\Omega$ connected to $V_S/2$, unless otherwise noted.



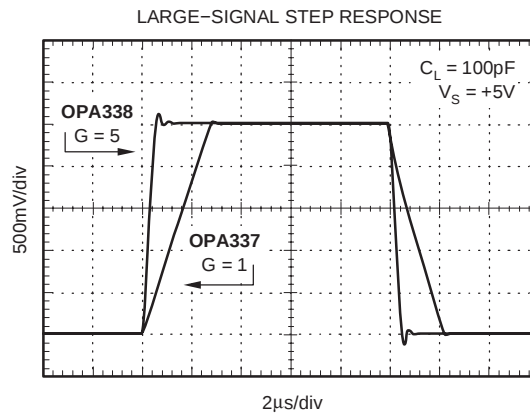
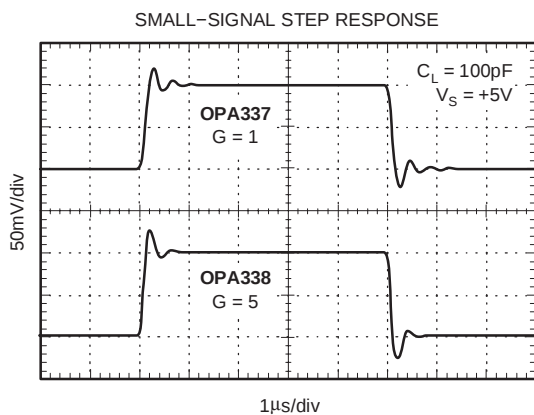
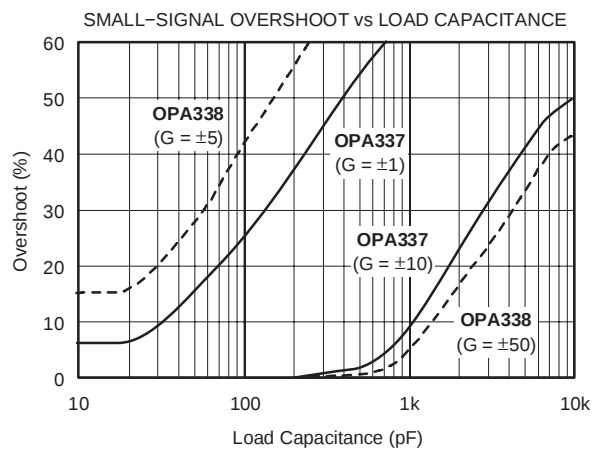
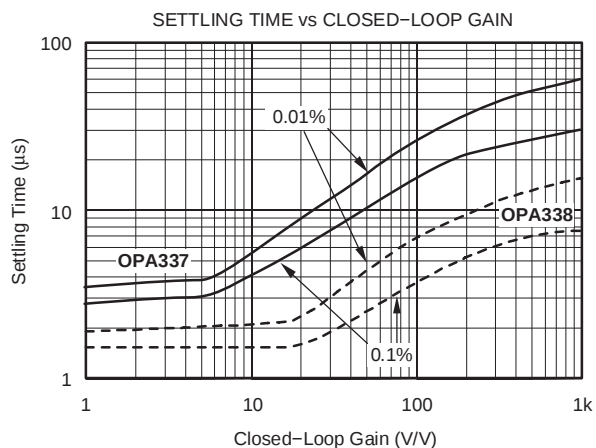
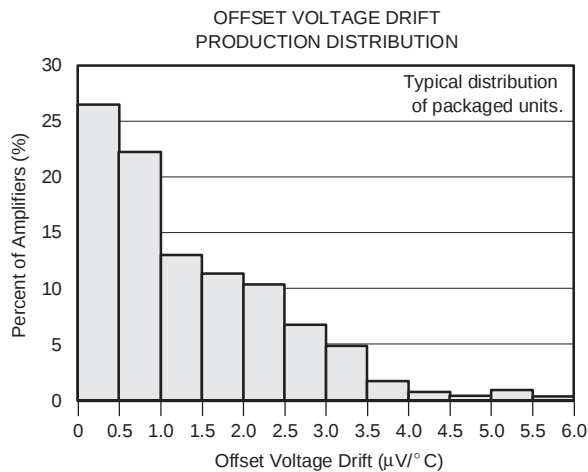
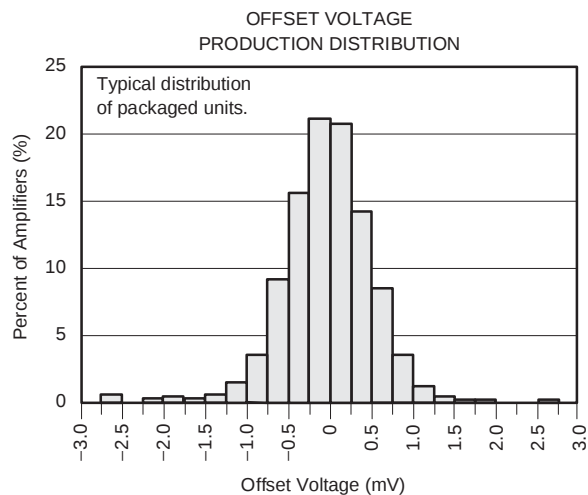
TYPICAL CHARACTERISTICS (continued)

At $T_A = +25^\circ\text{C}$, $V_S = +5\text{V}$, and $R_L = 25\text{k}\Omega$ connected to $V_S/2$, unless otherwise noted.



TYPICAL CHARACTERISTICS (continued)

At $T_A = +25^\circ\text{C}$, $V_S = +5\text{V}$, and $R_L = 25\text{k}\Omega$ connected to $V_S/2$, unless otherwise noted.



APPLICATIONS INFORMATION

The OPA337 and OPA338 series are fabricated on a state-of-the-art CMOS process. The OPA337 series is unity-gain stable. The OPA338 series is optimized for gains greater than or equal to 5. Both are suitable for a wide range of general-purpose applications. Power-supply pins should be bypassed with 0.01 μ F ceramic capacitors.

OPERATING VOLTAGE

The OPA337 series and OPA338 series can operate from a +2.5V to +5.5V single supply with excellent performance. Unlike most op amps which are specified at only one supply voltage, these op amps are specified for real-world applications; a single limit applies throughout the +2.7V to +5.5V supply range. This allows a designer to have the same assured performance at any supply voltage within the specified voltage range. Most behavior remains unchanged throughout the full operating voltage range. Parameters which vary significantly with operating voltage are shown in the Typical Characteristic curves.

INPUT VOLTAGE

The input common-mode range extends from (V₋) – 0.2V to (V₊) – 1.2V. For normal operation, inputs should be limited to this range. The absolute maximum input voltage is 500mV beyond the supplies. Inputs greater than the input common-mode range but less than maximum input voltage, while not valid, will not cause any damage to the op amp. Furthermore, if input current is limited the inputs may go beyond the power supplies without phase inversion (as shown in Figure 1) unlike some other op amps.

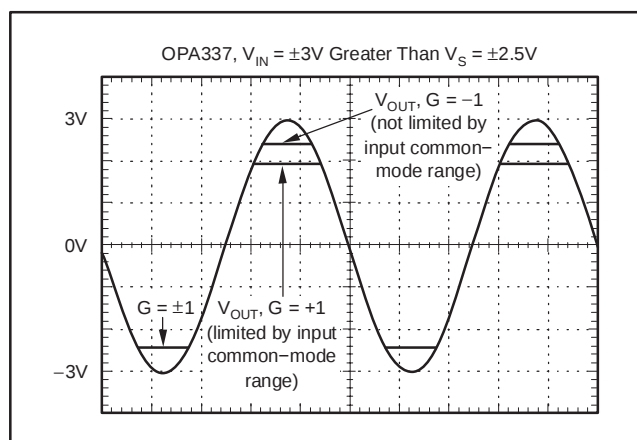


Figure 1. OPA337—No Phase Inversion with Inputs Greater than the Power-Supply Voltage

Normally, input currents are 0.2pA. However, large inputs (greater than 500mV beyond the supply rails) can cause excessive current to flow in or out of the input pins. Therefore, as well as keeping the input voltage below the maximum rating, it is also important to limit the input current to less than 10mA. This is easily accomplished with an input resistor as shown in Figure 2.

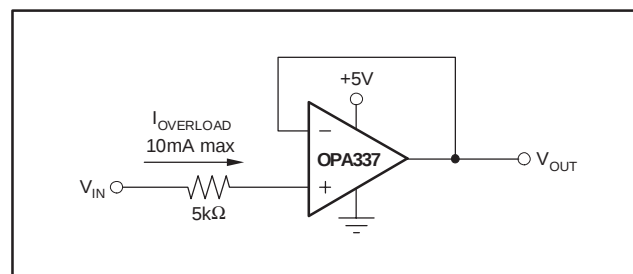


Figure 2. Input Current Protection for Voltages Exceeding the Supply Voltage

USING THE OPA338 IN LOW GAINS

The OPA338 series is optimized for gains greater than or equal to 5. It has significantly wider bandwidth (12.5MHz) and faster slew rate (4.6V/ μ s) when compared to the OPA337 series. The OPA338 series can be used in lower gain configurations at low frequencies while maintaining its high slew rate with the proper compensation.

Figure 3 shows the OPA338 in a unity-gain buffer configuration. At dc, the compensation capacitor C₁ is effectively open resulting in 100% feedback (closed-loop gain = 1). As frequency increases, C₁ becomes lower impedance and closed-loop gain increases, eventually becoming 1 + R₂/R₁ (in this case 5, which is equal to the minimum gain required for stability).

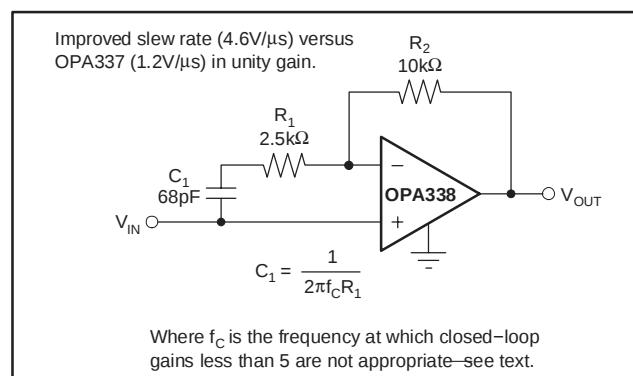


Figure 3. Compensation of the OPA338 for Unity-Gain Buffer

The required compensation capacitor value can be determined from the following equation:

$$C_1 = 1/(2\pi f_C R_1)$$

Since f_C may shift with process variations, it is recommended that a value less than f_C be used for determining C_1 . With $f_C = 1\text{MHz}$ and $R_1 = 2.5\text{k}\Omega$, the compensation capacitor is about 68pF.

The selection of the compensation capacitor C_1 is important. A proper value ensures that the closed-loop circuit gain is greater than or equal to 5 at high frequencies. Referring to the *Open-Loop Gain vs Frequency* plot in the Typical Characteristics section, the OPA338 gain line (dashed in the curve) has a constant slope (-20dB/decade) up to approximately 3MHz. This frequency is referred to as f_C . Beyond f_C the slope of the curve increases, suggesting that closed-loop gains less than 5 are not appropriate.

Figure 4 shows a compensation technique using an inverting configuration. The low-frequency gain is set by the resistor ratio while the high-frequency gain is set by the capacitor ratio. As with the noninverting circuit, for frequencies above f_C the gain must be greater than the recommended minimum stable gain for the op amp.

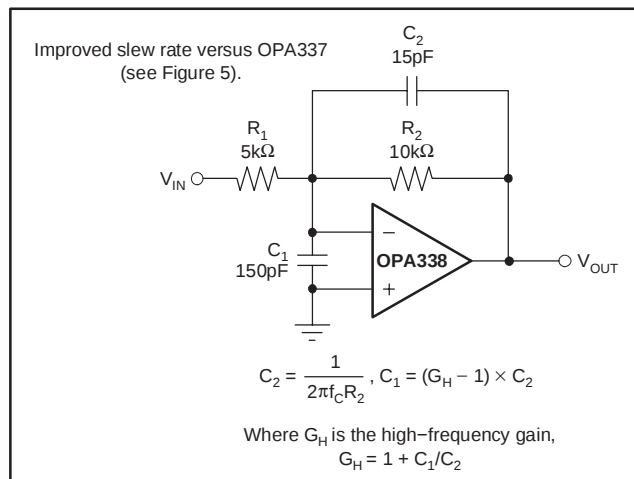


Figure 4. Inverting Compensation Circuit of the OPA338 for Low Gain

Resistors R_1 and R_2 are chosen to set the desired dc signal gain. Then the value for C_2 is determined as follows:

$$C_2 = 1/(2\pi f_C R_2)$$

C_1 is determined from the desired high-frequency gain (G_H):

$$C_1 = (G_H - 1) \times C_2$$

For a desired dc gain of 2 and high-frequency gain of 10, the following resistor and capacitor values result:

$$R_1 = 10\text{k}\Omega$$

$$C_1 = 150\text{pF}$$

$$R_2 = 5\text{k}\Omega$$

$$C_2 = 15\text{pF}$$

The capacitor values shown are the nearest standard values. Capacitor values may need to be adjusted slightly to optimize performance. For more detailed information, consult the section on *Low Gain Compensation* in the OPA846 data sheet (SBOS250) located at www.ti.com.

Figure 5 shows the large-signal transient response using the circuit given in Figure 4. As shown, the OPA338 is stable in low gain applications and provides improved slew rate performance when compared to the OPA337.

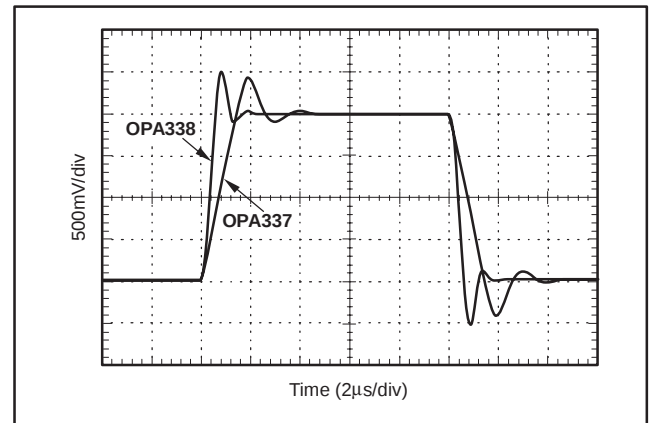


Figure 5. $G = 2$, Slew-Rate Comparison of the OPA338 and the OPA337

TYPICAL APPLICATION

See Figure 6 for the OPA2337 in a typical application. The ADS7822 is a 12-bit, micropower, sampling analog-to-digital converter available in the tiny MSOP-8 package. As with the OPA2337, it operates with a supply voltage as low as +2.7V. When used with the miniature SOT23-8 package of the OPA2337, the circuit is ideal for space-limited and low-power applications. In addition, the OPA2337's high input impedance allows large value resistors to be used which results in small physical capacitors, further reducing circuit size. For further information, consult the ADS7822 data sheet (SBAS062) located at www.ti.com.

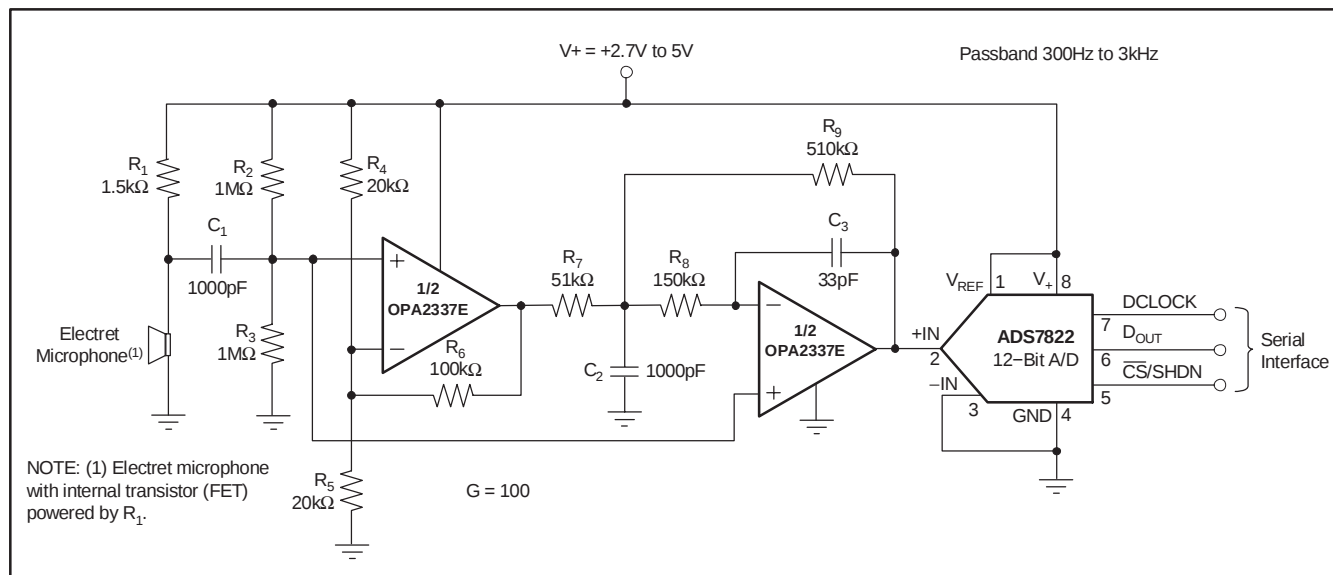


Figure 6. Low-Power, Single-Supply, Speech Bandpass Filtered Data Acquisition System

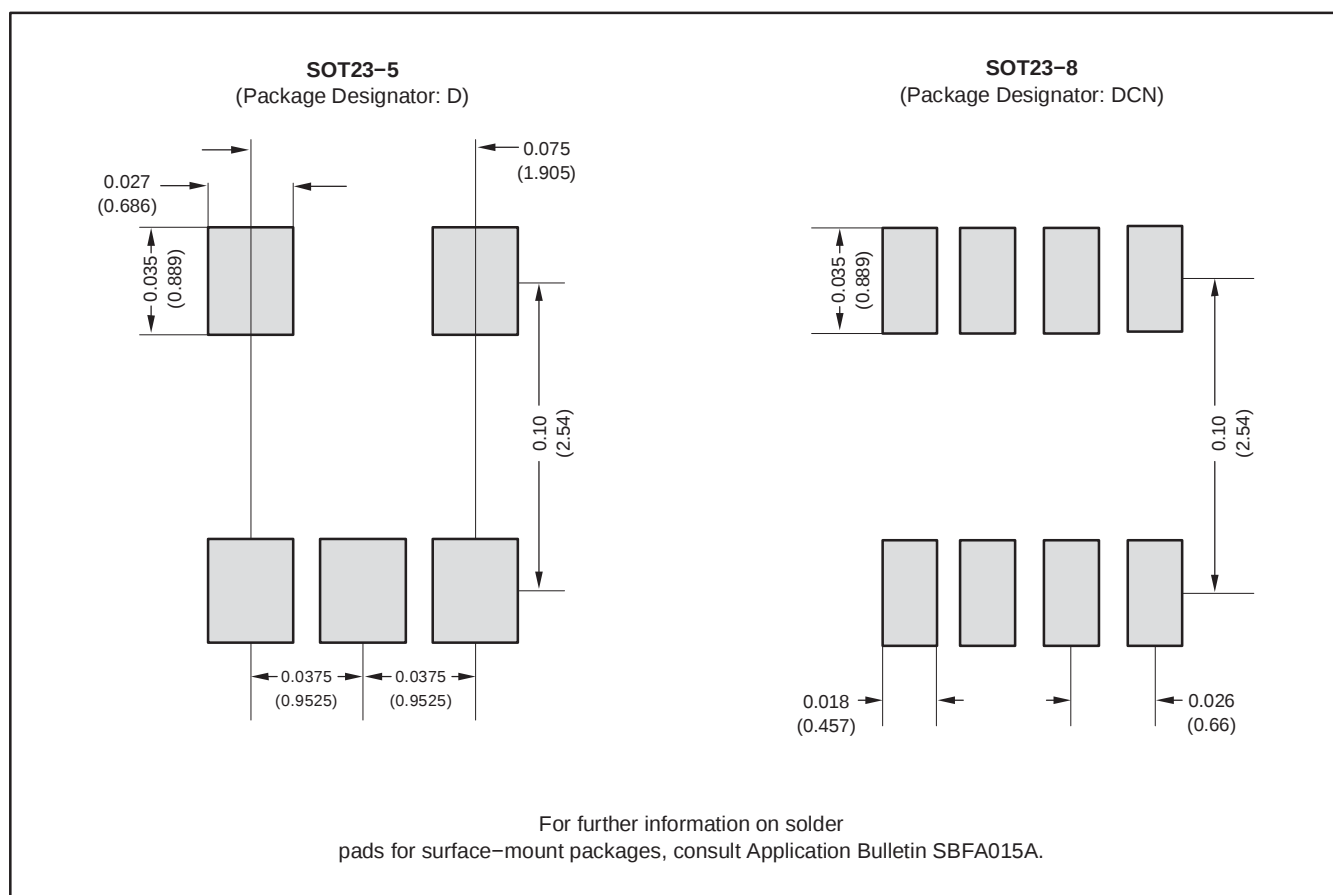


Figure 7. Recommended SOT23-5 and SOT23-8 Solder Footprints

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
OPA2337EA/250	Active	Production	SOT-23 (DCN) 8	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-	A7
OPA2337EA/250.B	Active	Production	SOT-23 (DCN) 8	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	A7
OPA2337EA/3K	Active	Production	SOT-23 (DCN) 8	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-	A7
OPA2337EA/3K.B	Active	Production	SOT-23 (DCN) 8	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	A7
OPA2337PA	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-	OPA2337PA
OPA2337PA.B	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	OPA2337PA
OPA2337UA	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-	OPA 2337UA
OPA2337UA.B	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 2337UA
OPA2337UA/2K5	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 2337UA
OPA2337UA/2K5.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 2337UA
OPA2337UA/2K5G4	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 2337UA
OPA2338EA/250	Active	Production	SOT-23 (DCN) 8	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-	A8
OPA2338EA/250.B	Active	Production	SOT-23 (DCN) 8	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	A8
OPA2338EA/250G4	Active	Production	SOT-23 (DCN) 8	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	A8
OPA2338EA/250G4.B	Active	Production	SOT-23 (DCN) 8	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	A8
OPA2338EA/3K	Active	Production	SOT-23 (DCN) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	A8
OPA2338EA/3K.B	Active	Production	SOT-23 (DCN) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	A8
OPA2338UA	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-	OPA 2338UA
OPA2338UA.B	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 2338UA
OPA2338UA/2K5	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 2338UA
OPA2338UA/2K5.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 2338UA
OPA337EA/250	Active	Production	VSSOP (DGK) 8	250 SMALL T&R	Yes	Call TI Nipdauag	Level-2-260C-1 YEAR	-40 to 85	G37

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
OPA337EA/250.B	Active	Production	VSSOP (DGK) 8	250 SMALL T&R	Yes	Call TI	Level-2-260C-1 YEAR	-40 to 85	G37
OPA337NA/250	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	C37
OPA337NA/250.B	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	C37
OPA337NA/250G4	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	C37
OPA337NA/3K	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	C37
OPA337NA/3K.B	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	C37
OPA337NA/3KG4	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	C37
OPA337UA	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 337UA
OPA337UA.B	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 337UA
OPA337UA/2K5	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 337UA
OPA337UA/2K5.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 337UA
OPA337UAG4	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 337UA
OPA338NA/250	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	A38
OPA338NA/250.B	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	A38
OPA338NA/3K	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	A38
OPA338NA/3K.B	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	A38
OPA338NA/3KG4	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	A38
OPA338NA/3KG4.B	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	A38
OPA338UA	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 338UA
OPA338UA.B	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 338UA
OPA338UAG4	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 338UA

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
OPA2337EA/250	SOT-23	DCN	8	250	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
OPA2337EA/3K	SOT-23	DCN	8	3000	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
OPA2337UA/2K5	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
OPA2338EA/250	SOT-23	DCN	8	250	180.0	8.4	3.15	3.1	1.55	4.0	8.0	Q3
OPA2338EA/250G4	SOT-23	DCN	8	250	180.0	8.4	3.15	3.1	1.55	4.0	8.0	Q3
OPA2338EA/3K	SOT-23	DCN	8	3000	180.0	8.4	3.15	3.1	1.55	4.0	8.0	Q3
OPA2338UA/2K5	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
OPA337NA/250	SOT-23	DBV	5	250	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
OPA337NA/250	SOT-23	DBV	5	250	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
OPA337NA/3K	SOT-23	DBV	5	3000	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
OPA337UA/2K5	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
OPA338NA/250	SOT-23	DBV	5	250	178.0	8.4	3.3	3.2	1.4	4.0	8.0	Q3
OPA338NA/3K	SOT-23	DBV	5	3000	178.0	8.4	3.3	3.2	1.4	4.0	8.0	Q3
OPA338NA/3KG4	SOT-23	DBV	5	3000	178.0	8.4	3.3	3.2	1.4	4.0	8.0	Q3

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
OPA2337EA/250	SOT-23	DCN	8	250	213.0	191.0	35.0
OPA2337EA/3K	SOT-23	DCN	8	3000	213.0	191.0	35.0
OPA2337UA/2K5	SOIC	D	8	2500	353.0	353.0	32.0
OPA2338EA/250	SOT-23	DCN	8	250	213.0	191.0	35.0
OPA2338EA/250G4	SOT-23	DCN	8	250	213.0	191.0	35.0
OPA2338EA/3K	SOT-23	DCN	8	3000	213.0	191.0	35.0
OPA2338UA/2K5	SOIC	D	8	2500	353.0	353.0	32.0
OPA337NA/250	SOT-23	DBV	5	250	203.0	203.0	35.0
OPA337NA/250	SOT-23	DBV	5	250	180.0	180.0	18.0
OPA337NA/3K	SOT-23	DBV	5	3000	180.0	180.0	18.0
OPA337UA/2K5	SOIC	D	8	2500	353.0	353.0	32.0
OPA338NA/250	SOT-23	DBV	5	250	565.0	140.0	75.0
OPA338NA/3K	SOT-23	DBV	5	3000	565.0	140.0	75.0
OPA338NA/3KG4	SOT-23	DBV	5	3000	565.0	140.0	75.0

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
OPA2337PA	P	PDIP	8	50	506	13.97	11230	4.32
OPA2337PA.B	P	PDIP	8	50	506	13.97	11230	4.32
OPA2337UA	D	SOIC	8	75	506.6	8	3940	4.32
OPA2337UA.B	D	SOIC	8	75	506.6	8	3940	4.32
OPA2338UA	D	SOIC	8	75	506.6	8	3940	4.32
OPA2338UA.B	D	SOIC	8	75	506.6	8	3940	4.32
OPA337UA	D	SOIC	8	75	506.6	8	3940	4.32
OPA337UA.B	D	SOIC	8	75	506.6	8	3940	4.32
OPA337UAG4	D	SOIC	8	75	506.6	8	3940	4.32
OPA338UA	D	SOIC	8	75	506.6	8	3940	4.32
OPA338UA.B	D	SOIC	8	75	506.6	8	3940	4.32
OPA338UAG4	D	SOIC	8	75	506.6	8	3940	4.32



SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



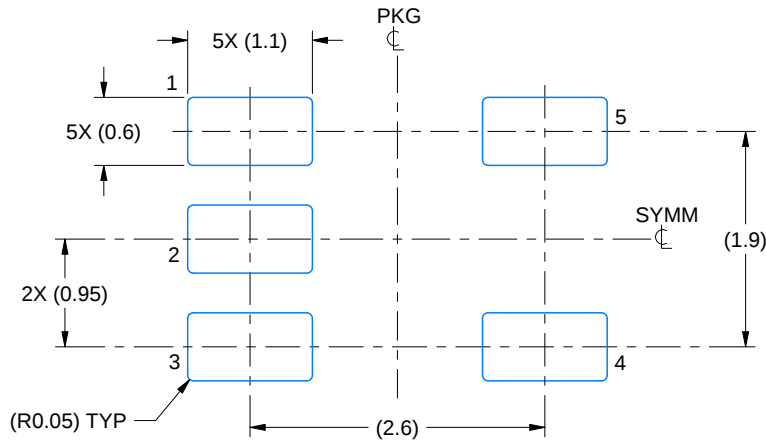
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC MO-178.
4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
5. Support pin may differ or may not be present.

EXAMPLE BOARD LAYOUT

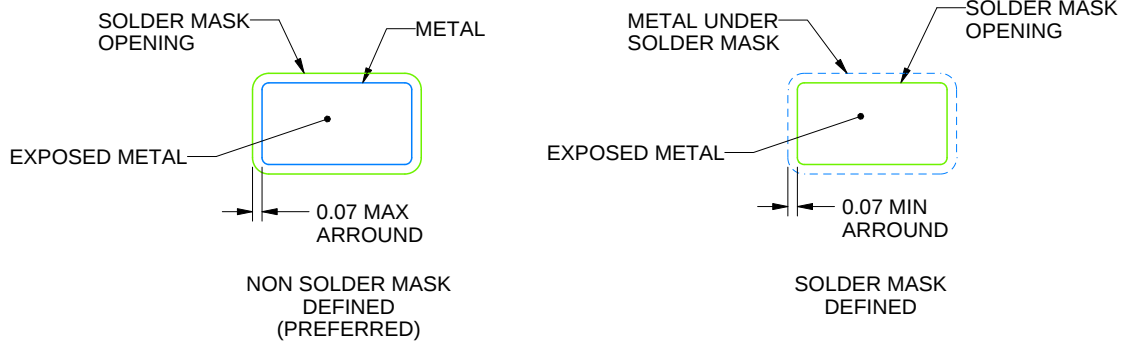
DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X



SOLDER MASK DETAILS

4214839/K 08/2024

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



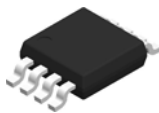
SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214839/K 08/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

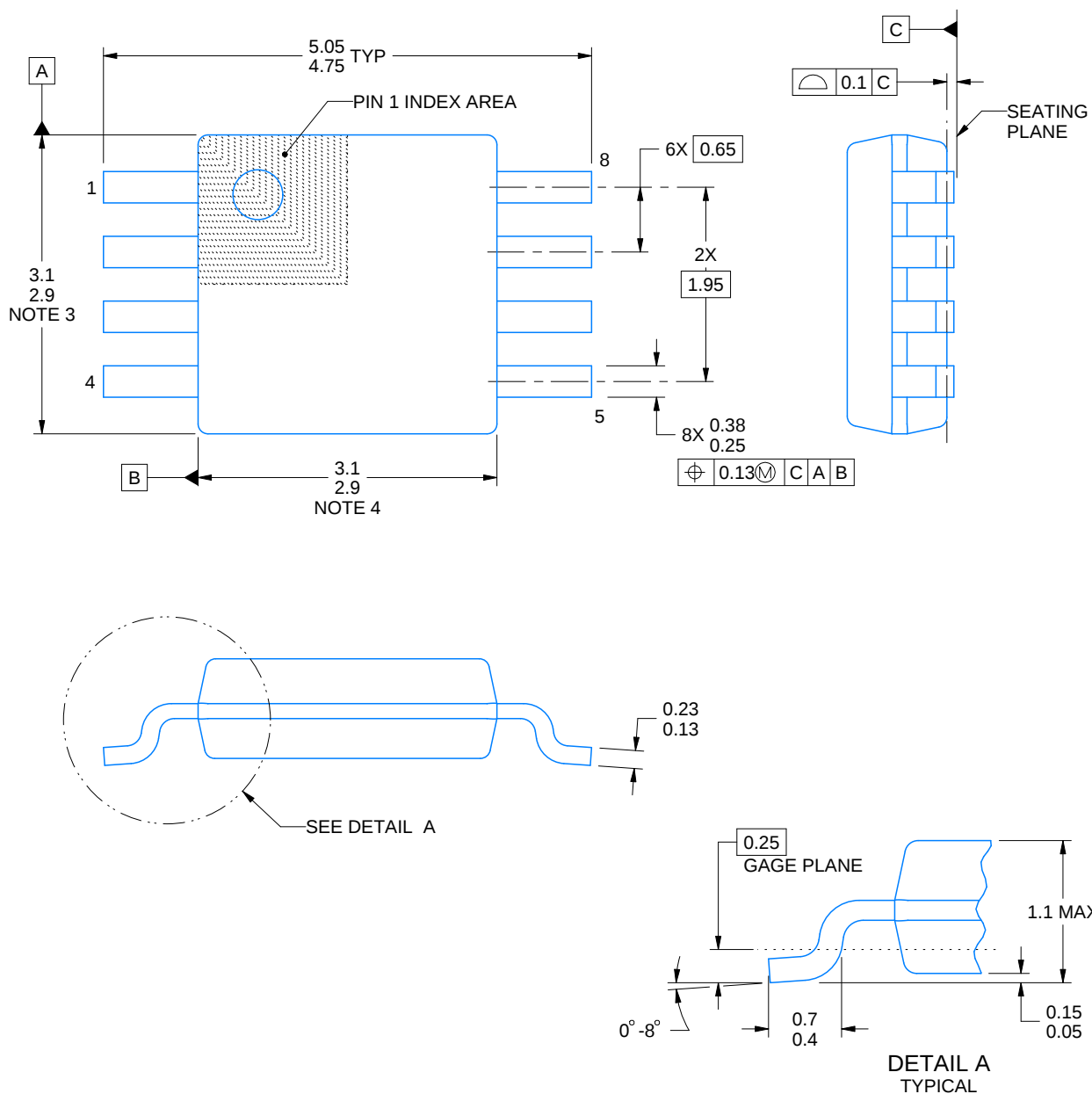
DGK0008A



PACKAGE OUTLINE

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



4214862/A 04/2023

NOTES:

PowerPAD is a trademark of Texas Instruments.

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.

EXAMPLE BOARD LAYOUT

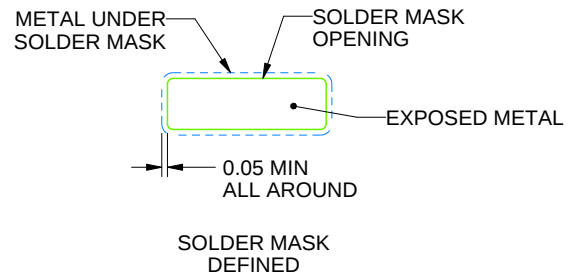
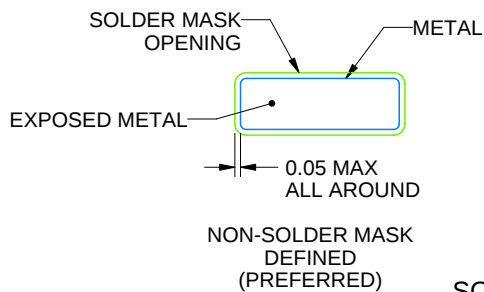
DGK0008A

TM VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 15X



SOLDER MASK DETAILS

4214862/A 04/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.

EXAMPLE STENCIL DESIGN

DGK0008A

TM VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
SCALE: 15X

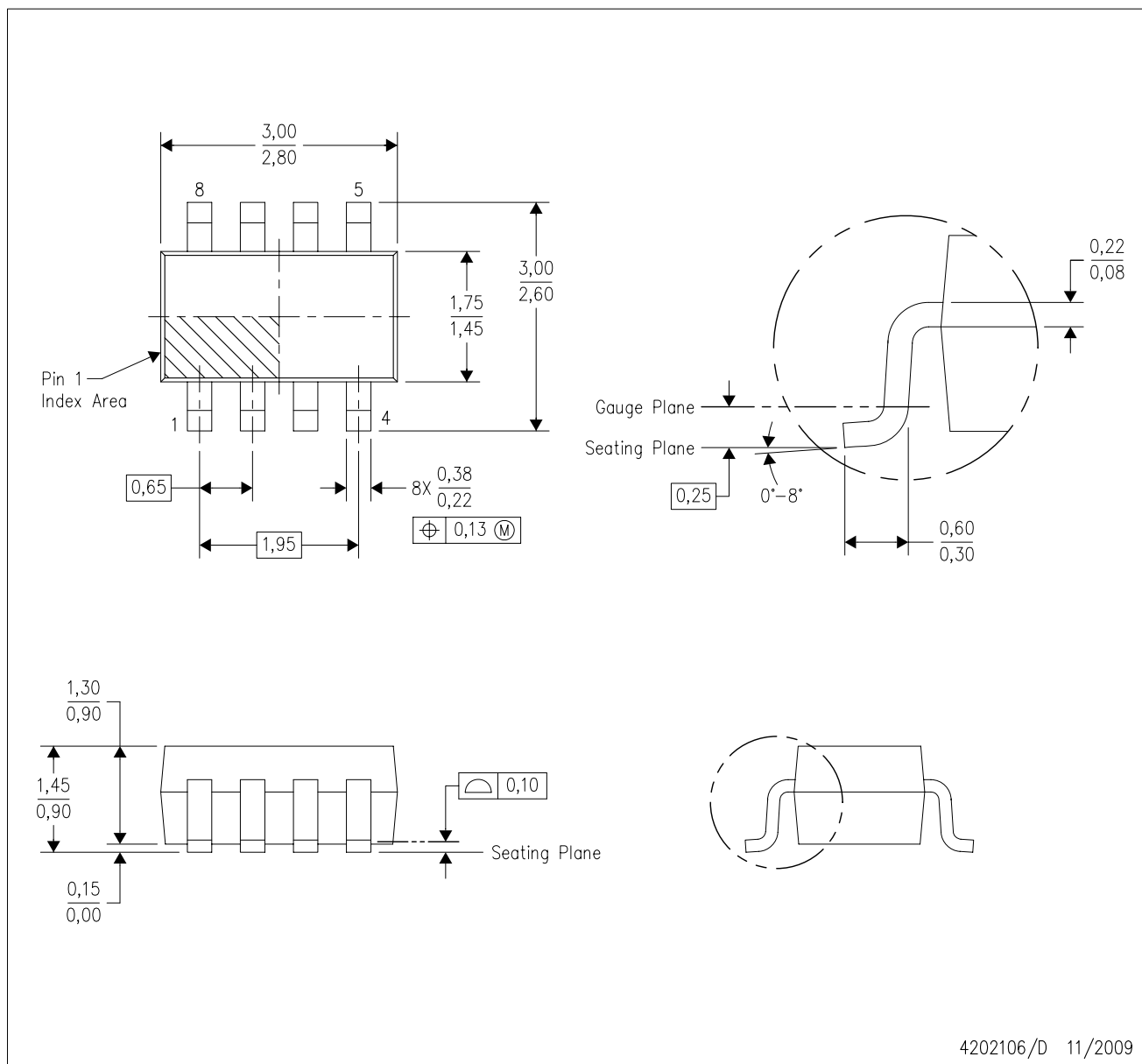
4214862/A 04/2023

NOTES: (continued)

11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
12. Board assembly site may have different recommendations for stencil design.

DCN (R-PDSO-G8)

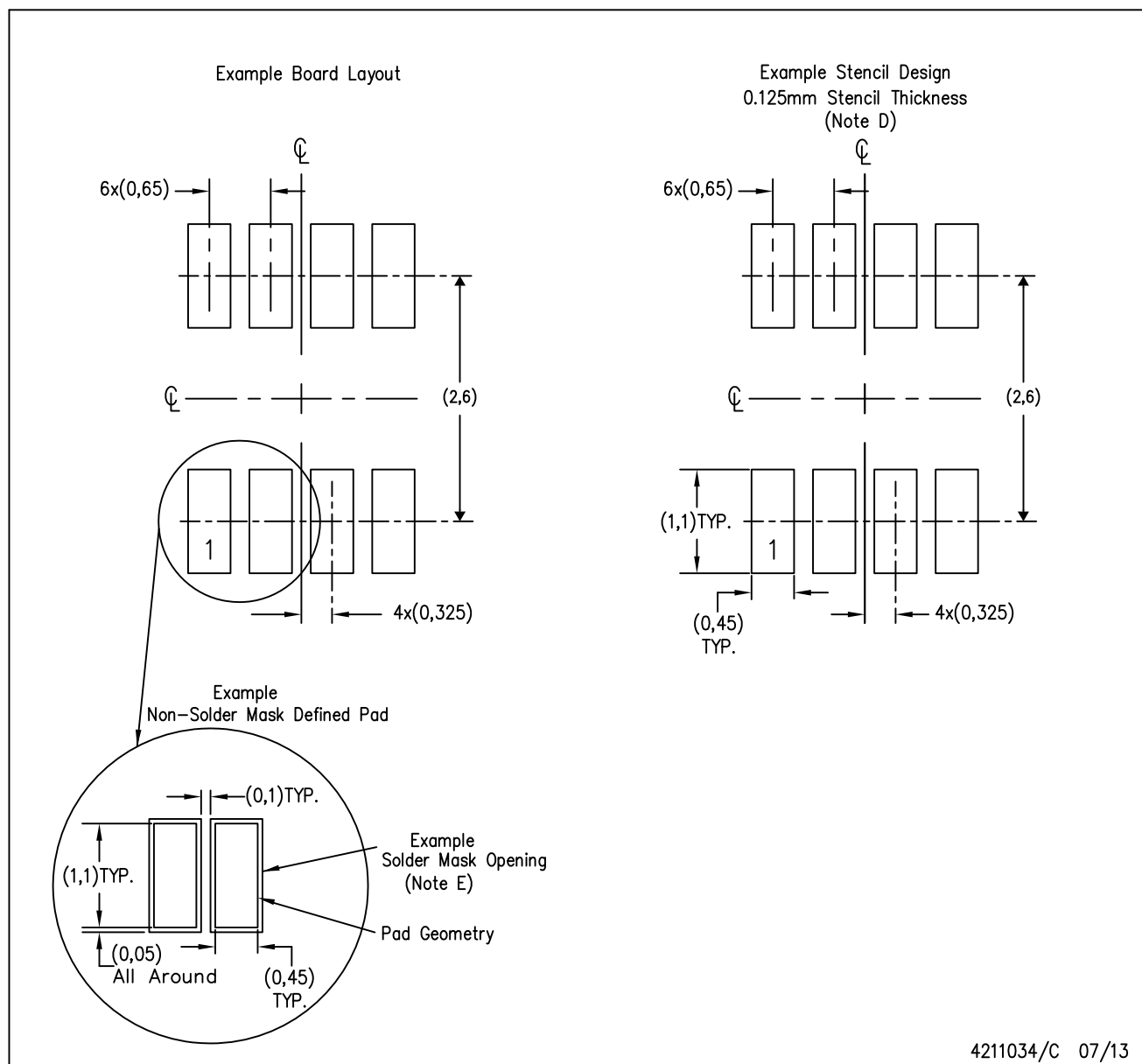
PLASTIC SMALL-OUTLINE PACKAGE (DIE DOWN)



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Package outline exclusive of metal burr & dambar protrusion/intrusion.
 - D. Package outline inclusive of solder plating.
 - E. A visual index feature must be located within the Pin 1 index area.
 - F. Falls within JEDEC MO-178 Variation BA.
 - G. Body dimensions do not include flash or protrusion. Mold flash and protrusion shall not exceed 0.25 per side.

DCN (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE (DIE DOWN)



- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Publication IPC-7351 is recommended for alternate designs.
 - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525.
 - Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Falls within JEDEC MS-001 variation BA.

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